January 30, 2008

M185/LM285/LM385 Adjustable Micropower Voltage Reference



# LM185/LM285/LM385 Adjustable Micropower Voltage References

### **General Description**

The LM185/LM285/LM385 are micropower 3-terminal adjustable band-gap voltage reference diodes. Operating from 1.24 to 5.3V and over a 10 $\mu$ A to 20mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185 band-gap reference uses only transistors and resistors, low noise and good long-term stability result.

Careful design of the LM185 has made the device tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life. Further, the

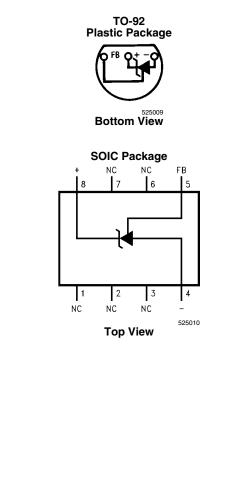
wide operating current allows it to replace older references with a tighter tolerance part.

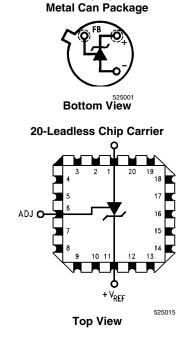
The LM185 is rated for operation over a -55°C to 125°C temperature range, while the LM285 is rated -40°C to 85°C and the LM385 0°C to 70°C. The LM185 is available in a hermetic TO-46 package and a leadless chip carrier package, while the LM285/LM385 are available in a low-cost TO-92 molded package, as well as S.O.

### **Features**

- Adjustable from 1.24V to 5.30V
- Operating current of 10µA to 20mA
- 1% and 2% initial tolerance
- 1Ω dynamic impedance
- Low temperature coefficient







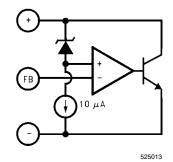
TO-46

LM185/LM285/LM385

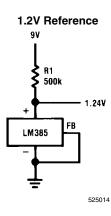
### **Ordering Information**

Package		Temperature Range		NSC Drawing
–55°C to 125°C	–40°C to 85°C	0°C to 70°C		
	LM185BH			
TO-46	LM185BH/883			ПОЭП
10-40	LM185BYH			Н03Н
Γ	LM185BYH/883			
TO-92		LM285BXZ	LM385BXZ	
		LM285BYZ	LM385BYZ	7024
		LM285Z	LM385BZ	Z03A
			LM385Z	
8-Pin SOIC		LM285M	LM385M	1400.4
		LM285BYM	LM385BM	— M08A
20-Leadless Chip Carrier	LM185BE/883			E20A

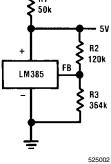
### **Block Diagram**

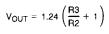


## **Typical Applications**



5.0V Reference





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### Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

(Note 2)	
Reverse Current	30mA
Forward Current	10mA
Operating Temperature Range (Note 3)	
LM185 Series	–55°C to 125°C
LM285 Series	–40°C to 85°C
LM385 Series	0°C to 70°C

### ESD Susceptibility (Note 8) 2kV Storage Temperature -55°C to 150°C Soldering Information TO-92 Package (10 sec.) 260°C TO-46 Package (10 sec.) 300°C SO Package Vapor Phase (60 sec.) 215°C Infrared (15 sec.) 220°C

See An-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

## Electrical Characteristics (Note 4)

		LM185, LM285			LM385							
Parameter	Conditions	-	LM185BX, LM185BY LM185B, LM285BX, LM285BY		LM285		Тур	LM385BX, LM385BY		LM385		Units (Limit)
		Тур		Design	Tested	Design	тур	Tested	Design	Tested	Design	
			Limit	Limit	Limit	Limit		Limit	Limit	Limit	Limit	
			(Note	(Note	(Note	(Note		(Note	(Note	(Note	(Note	
			5)	6)	5)	6)		5)	6)	5)	6)	
Reference	1 - 400-4	1.240	1.252	0)	1.265	1.270	1.240	1.252	1.255	1.265		V
Voltage	Ι <sub>R</sub> = 100μΑ	1.240	1.202		1.205	1.270	1.240	1.202	1.255	1.205	1.270	V V
vollage			1.255									(max)
			1.228		1.215	1.205		1.228	1.215	1.215	1.205	V (IIIAX)
			1.220		1.215	1.205		1.220	1.215	1.215	1.205	-
Deference		0.0		1.5		15	0.0		1.5	4	1.5	(min)
Reference Voltage	I <sub>MIN</sub> < I <sub>R</sub> < 1mA	0.2	1	1.5	1	1.5	0.2	1	1.5	1	1.5	mV
Change with Current	1mA < I <sub>R</sub> < 20mA	4	10	20	10	20	5	15	25	15	25	(max)
Dynamic Output Impedance	$I_R = 100\mu A$ , $f =$ 100Hz $I_{AC} = 0.1 I_R$ $V_{OUT} =$	0.3					0.4					
F	$V_{\text{REF}}$ $V_{\text{OUT}} = 5.3 \text{V}$	0.7					1					Ω
Reference	Ι <sub>R</sub> = 100μΑ											mV
Voltage Change with Output Voltage		1	3	6	3	6	2	5	10	5	10	(max)
Feedback Current		13	20	25	20	25	16	30	35	30	35	nA (max)
Minimum Operating	V <sub>OUT</sub> = V <sub>REF</sub>	6	9	10	9	10	7	11	13	11	13	μA
Current (see curve)	V <sub>OUT</sub> = 5.3V	30	45	50	45	50	35	55	60	55	60	(max)
Output Wideband	I <sub>R</sub> = 100µA, 10Hz < f < 10kHz											
Noise	$V_{OUT} = V_{REF}$	50					50					μV <sub>rms</sub>
	$V_{OUT} = 5.3V$	170					170					r ms

	Parameter Conditions		LM185, LM285					LM385					
Parameter			Тур	LM185BX, LM185BY LM185B, LM285BX, LM285BY		LM285		Тур	LM385BX, LM385BY		LM385		Units (Limit)
					Design		Design		Tested	U U		Design	
				Limit	Limit	Limit	Limit		Limit	Limit	Limit	Limit	
				(Note	(Note	(Note	(Note		(Note	(Note	(Note	(Note	
				5)	6)	5)	6)		5)	6)	5)	6)	
Average	Ι <sub>Β</sub> = 100μΑ	X Suffix		30					30				ppm/°
Temperature													с
Coefficient		Y Suffix		50					50				(max)
(Note 7)													
		All			150		150			150		150	
		Others											
Long Term	I <sub>R</sub> = 100μA, <sup>-</sup>	Γ = 1000	20					20					ppm
Stability	Hr,												
	$T_{\Delta} = 25^{\circ}C \pm$	0.1°C											

**Note 1:** Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Refer to RETS185H for military specifications.

Note 3: For elevated temperature operation, T<sub>J</sub>max is:

LM18	5 150°C		
LM28	5 125°C		
LM38	5 100°C		
Thermal Resistance	TO-92	TO-46	SO-8
$\theta_{JA}$ (Junction to Ambient)	180°C/W (0.4 leads)	440°C/W	165°C/W
	170°C/W (0.125 leads)		
$\theta_{JC}$ (Junction to Case)	N/A	80°C/W	N/A

Note 4: Parameters identified with **boldface type** apply at temperature extremes. All other numbers apply at  $T_A = T_J = 25^{\circ}C$ . Unless otherwise specified, all parameters apply for  $V_{REF} < V_{OUT} < 5.3V$ .

Note 5: Guaranteed and 100% production tested.

Note 6: Guaranteed, but not 100% production tested. These limits are not to be used to calculate average outgoing quality levels.

Note 7: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures from  $T_{MIN}$  to  $T_{MAX}$ , divided by  $T_{MAX} - T_{MIN}$ . The measured temperatures are -55, -40, 0, 25, 70, 85, 125°C.

4

Note 8: The human body model is a 100 pF capacitor discharged through a 1.5  $k\Omega$  resistor into each pin.

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Feedback Current

- 50 - 25

0

VOUT = VREF

= 25°Ċ

TA 1

> 0 0.2

۵

0.01

25

**Reverse Characteristics** 

TA

**TEMPERATURE (°C)** 

 $IR = 100 \ \mu A$ 

VOUT = VREF

= 5.3V

100 125

-55°C

525019

525017

Vout

50 75

55°C

0.4 0.6 0.8 1.0 1.2 1.4

10

100

525021

**REVERSE VOLTAGE (V)** 

**Forward Characteristics** 

55°C

125°C

0.1

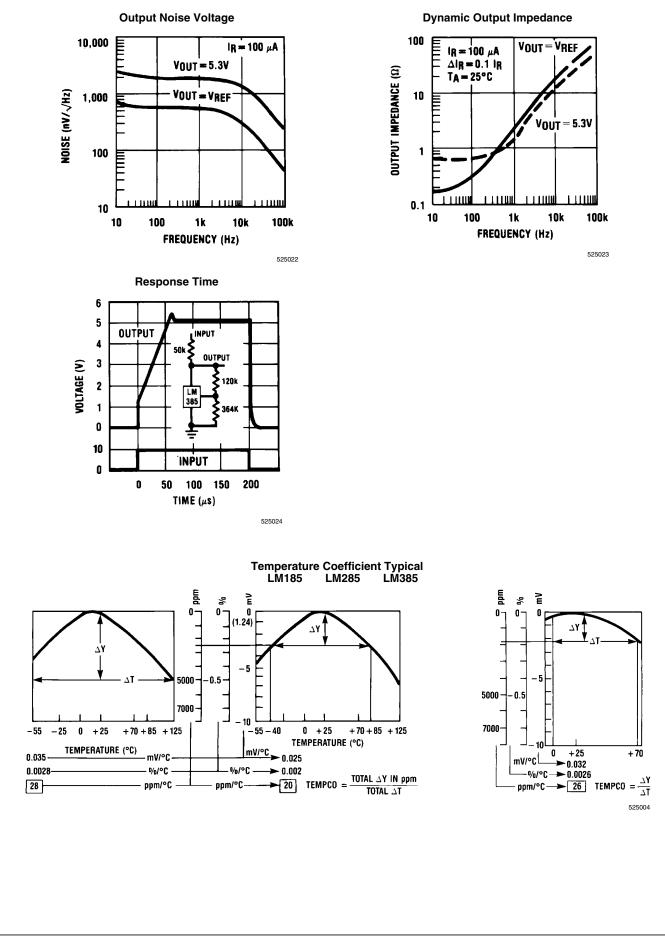
#### **Typical Performance Characteristics** Temperature Drift of 3 Representative Units 25 1.260 FEEDBACK CURRENT (nA) 20 REFERENCE VOLTAGE (V) 1.250 15 1.240 10 1.230 5 1.220 0 -55-35-15 5 25 45 65 85 105 125 **TEMPERATURE (°C)** 525016 **Minimum Operating Current** 100 80 70 WORST MINIMUM CURRENT (µA) REVERSE CURRENT (µA) 60 CASE 10 LM385 50 WORST 40 CASE LM185 30 20 TYP @ 25°C 10 0.1 0 1 2 3 4 5 6 • **OUTPUT VOLTAGE (V)** 525018 **Reverse Characteristics** 10 1.2 TTH - VREF Vout **OUTPUT VOLTAGE CHANGE (mV)** 8 FORWARD VOLTAGE (V) 25 °C 6 0.8 4 0.4 2 0 2 0.01 0.1 10 100 1 **REVERSE CURRENT (mA)** 525020

1

FORWARD CURRENT (mA)

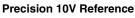
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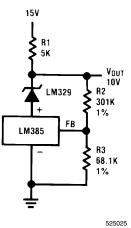




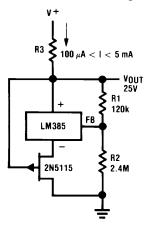
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## **Typical Applications**

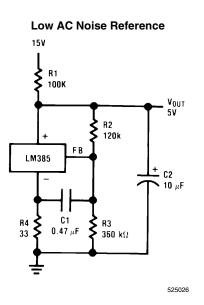




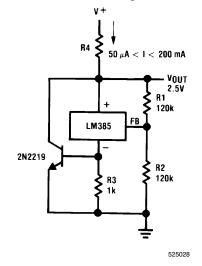
25V Low Current Shunt Regulator

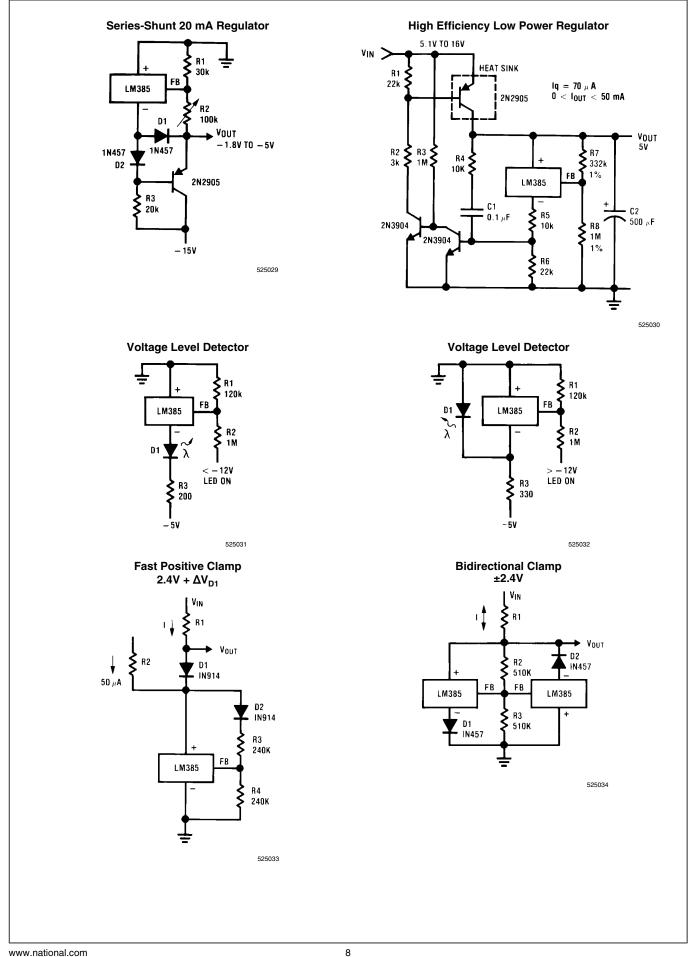


525027

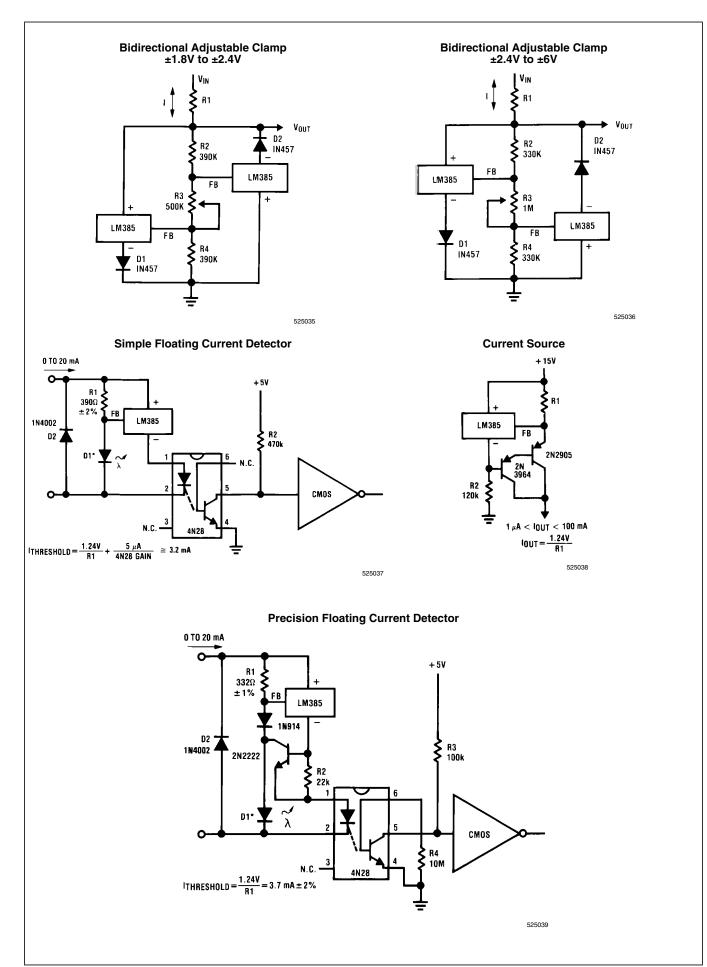


200 mA Shunt Regulator

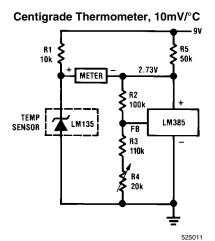


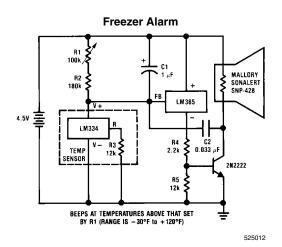


LM185/LM285/LM385

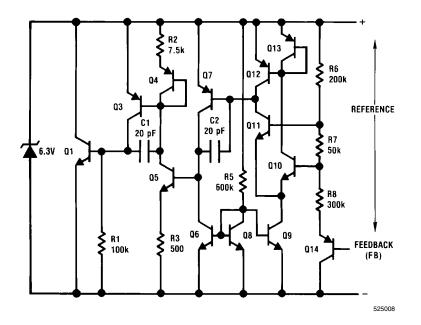


\*D1 can be any LED, V<sub>F</sub>=1.5V to 2.2V at 3 mA. D1 may act as an indicator. D1 will be on if I<sub>THRESHOLD</sub> falls below the threshold current, except with I=O.

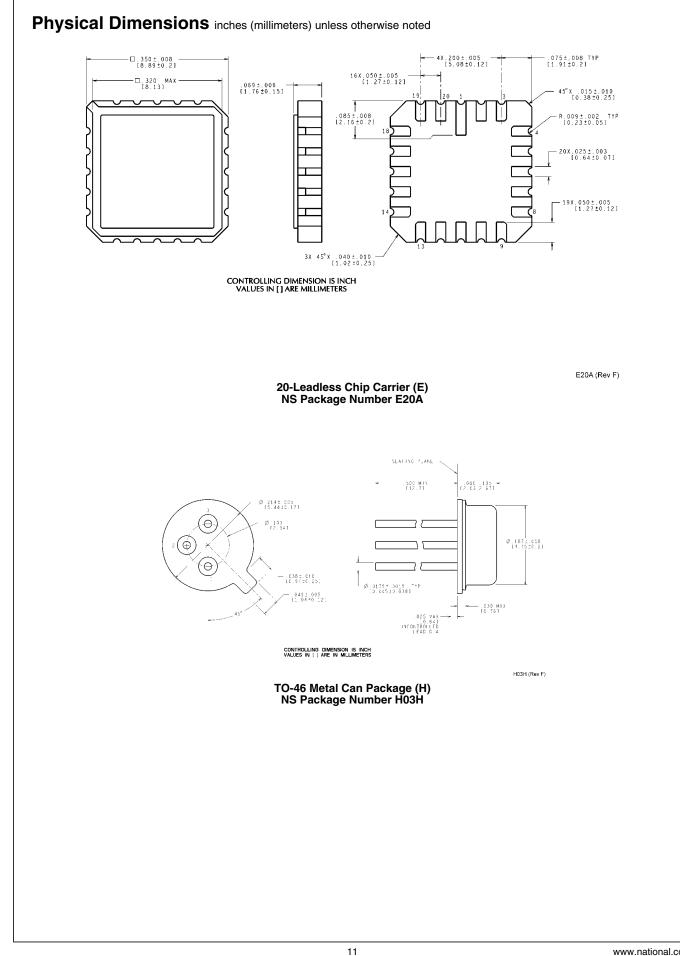




**Schematic Diagram** 

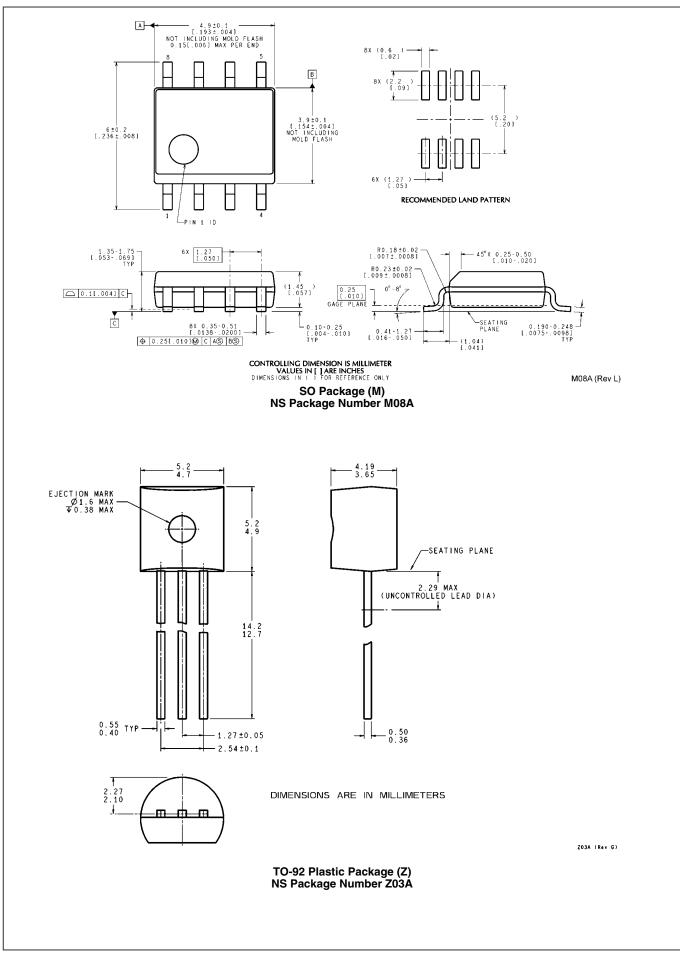


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LM185/LM285/LM385







Notes

# **Notes**

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Displays	www.national.com/displays	Green Compliance	www.national.com/quality/green					
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